

## isc N-Channel MOSFET Transistor

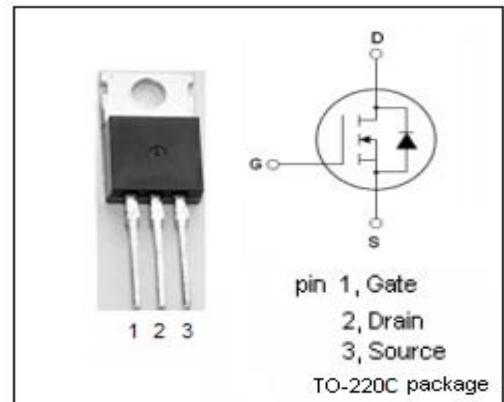
## TK17E80W, ITK17E80W

### • FEATURES

- Low drain-source on-resistance:  
 $R_{DS(on)} \leq 0.29\Omega$ .
- Enhancement mode:  
 $V_{TH} = 3.0$  to  $4.0\text{V}$  ( $V_{DS} = 10\text{V}$ ,  $I_D = 0.85\text{mA}$ )
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### • DESCRIPTION

- Switching Voltage Regulators

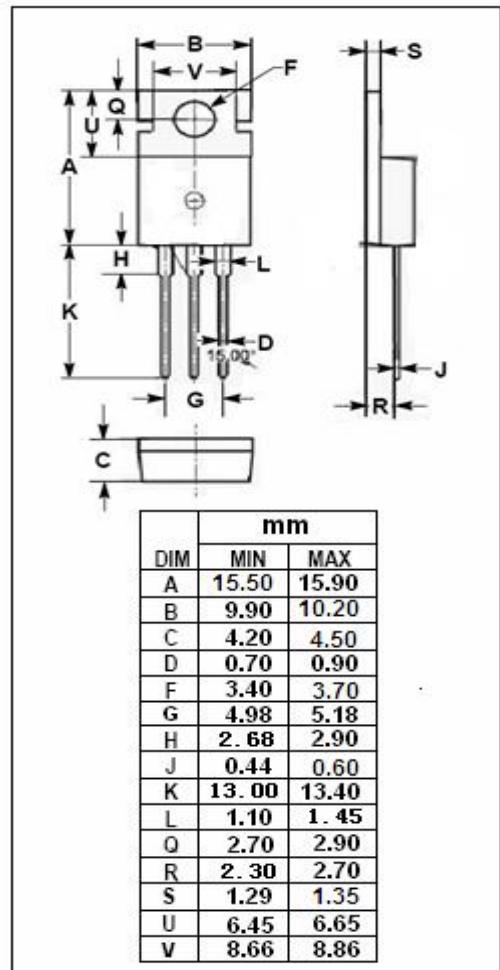


### • ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	800	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous	17	A
$I_{DM}$	Drain Current-Single Pulsed	68	A
$P_D$	Total Dissipation @ $T_c=25^\circ\text{C}$	180	W
$T_j$	Max. Operating Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~150	$^\circ\text{C}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.694	$^\circ\text{C}/\text{W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	83.3	$^\circ\text{C}/\text{W}$



**isc N-Channel MOSFET Transistor      TK17E80W, ITK17E80W****ELECTRICAL CHARACTERISTICS****T<sub>c</sub>=25°C unless otherwise specified**

<b>SYMBOL</b>	<b>PARAMETER</b>	<b>CONDITIONS</b>	<b>MIN</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =10mA	800			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =10V; I <sub>D</sub> =0.85mA	3.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =8.5A			0.29	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V; V <sub>DS</sub> = 0V			±1	μ A
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =800V; V <sub>GS</sub> = 0V			10	μ A
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =17A, V <sub>GS</sub> = 0 V			1.7	V

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